

### General Description

MBRB20100CTLV Device optimized for ultra-low forward voltage drop to maximize efficiency in Power Supply applications.

### Features

- Common Cathode
- Low Leakage Current
- High Current Capability, High Efficiency
- RoHS Compliant

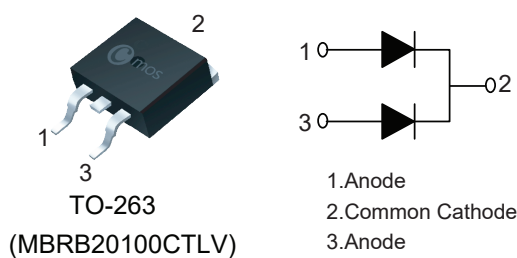
### Product Summary

| $V_{RRM}$ | $V_F$ | $I_{F(AV)}$ |
|-----------|-------|-------------|
| 100V      | 0.75V | 20A         |

### Applications

- DC/DC converter
- Switched Mode Power Supplies (SMPS)
- Low Voltage High Frequency Invers Circuit

### TO-220 Pin Configuration



### Absolute Maximum Ratings

| Symbol      | Parameter                                                                                | Rating                     | Units |
|-------------|------------------------------------------------------------------------------------------|----------------------------|-------|
| $V_{RRM}$   | Peak Repetitive Reverse Voltage                                                          | 100                        | V     |
| $I_{F(AV)}$ | Average Rectified Forward Current (Rated VR-20Khz Square Wave) - 50% duty cycle          | 10 (Per Leg)<br>20 (Total) | A     |
| dv/dt       | Voltage rate of change (Rated VR)                                                        | 10000                      | V/uS  |
| $I_{RRM}$   | Peak Repetitive Reverse Surge Current (2uS, 1Khz)                                        | 0.5                        | A     |
| $I_{FSM}$   | Forward Peak Surge Current (Rated Load 8.3ms Half Mssine Wave-According to JEDEC Method) | 160x2                      | A     |
| $T_J$       | Operating Junction Temperature                                                           | 150                        | °C    |
| $T_{STG}$   | Storage Temperature                                                                      | -40 to 150                 | °C    |

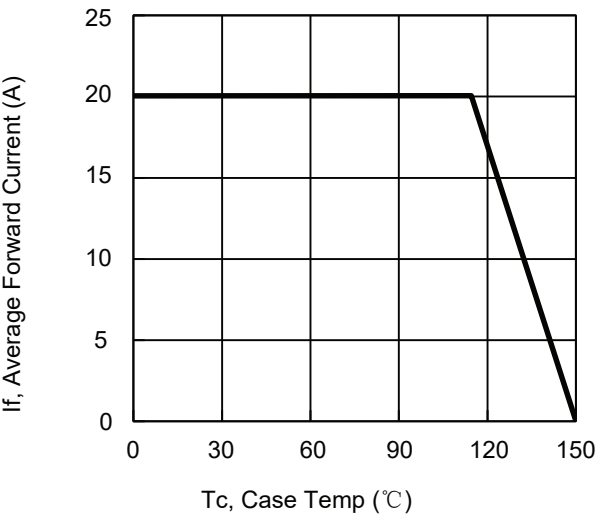
### Thermal Data

| Symbol          | Parameter                                      | Typ. | Max. | Unit |
|-----------------|------------------------------------------------|------|------|------|
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case (Per Leg) | 2    | ---  | °C/W |

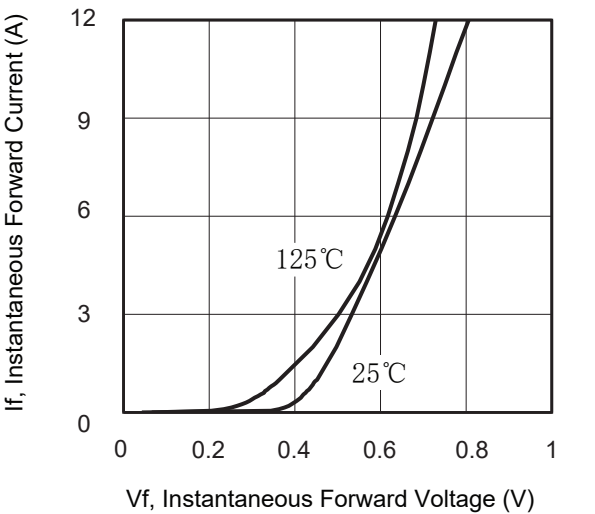
Electrical Characteristics

| Symbol | Parameter                         | Conditions                   | Min. | Typ. | Max.  | Unit |
|--------|-----------------------------------|------------------------------|------|------|-------|------|
| $V_F$  | Forward Voltage Drop per diode    | $I_F=10A, T_C=25^{\circ}C$   | ---  | 0.65 | 0.75  | V    |
|        |                                   | $I_F=10A, T_C=125^{\circ}C$  | ---  | ---  | 0.7   |      |
| $I_R$  | Reverse Leakage Current per diode | $V_R=100V, T_C=25^{\circ}C$  | ---  | ---  | 0.035 | mA   |
|        |                                   | $V_R=100V, T_C=125^{\circ}C$ | ---  | ---  | 15    | mA   |

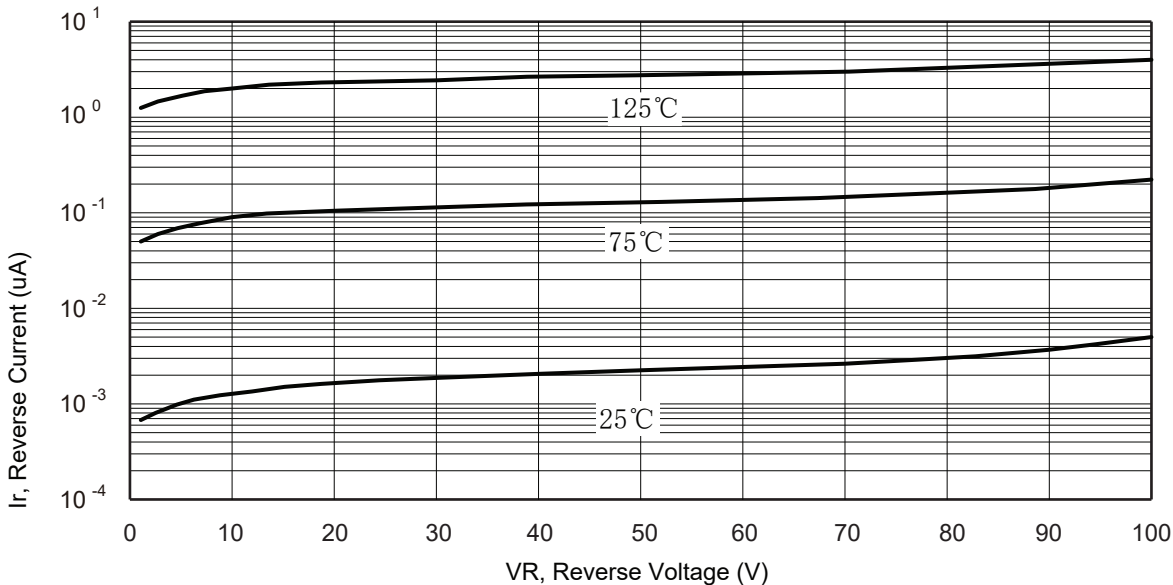
Performance Characteristics



Current derating curve, per element



The forward voltage and forward current curve



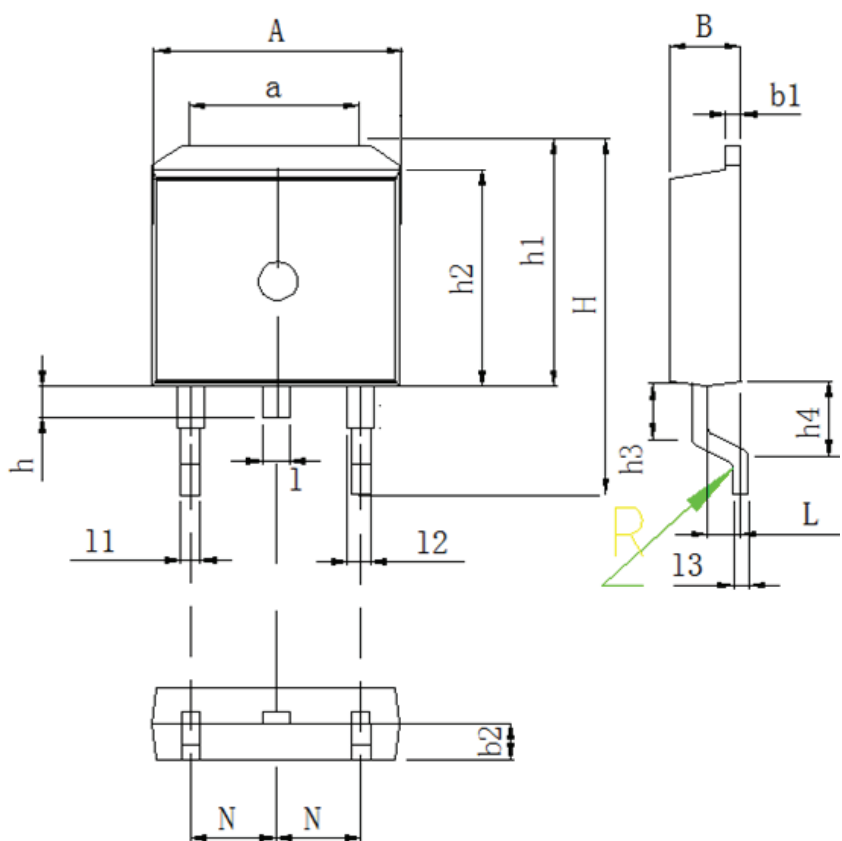
The reverse leak current and the reverse voltage (single-device) curve

This product has been designed and qualified for the consumer market.  
Cmos assumes no liability for customers' product design or applications.  
Cmos reserves the right to improve product design, functions and reliability without notice. Please refer to the latest version of specification.

Package Dimension

TO-263

Unit :mm



| DIM | MILLIMETERS     |
|-----|-----------------|
| A   | $9.8 \pm 0.2$   |
| a   | $7.4 \pm 0.4$   |
| B   | $4.5 \pm 0.2$   |
| b1  | $1.3 \pm 0.05$  |
| b2  | $2.4 \pm 0.2$   |
| H   | $15.5 \pm 0.3$  |
| h   | $1.54 \pm 0.2$  |
| h1  | $10.5 \pm 0.2$  |
| h2  | $9.2 \pm 0.1$   |
| h3  | $1.54 \pm 0.2$  |
| h4  | $2.7 \pm 0.2$   |
| L   | $2.4 \pm 0.2$   |
| 1   | $1.3 \pm 0.1$   |
| 11  | $0.8 \pm 0.1$   |
| 12  | $1.3 \pm 0.1$   |
| 13  | $0.5 \pm 0.1$   |
| N   | $2.54 \pm 0.1$  |
| R   | $0.5R \pm 0.05$ |